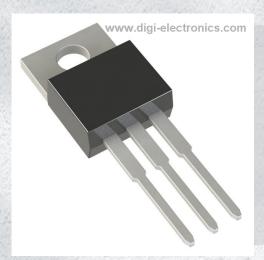


IXTP5N60P Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXTP5N60P-DG

Manufacturer IXYS

Manufacturer Product Number IXTP5N60P

Description MOSFET N-CH 600V 5A TO220AB

Detailed Description N-Channel 600 V 5A (Tc) 100W (Tc) Through Hole T

0-220-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTP5N60P	IXYS
Series:	Product Status:
PolarHV™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
600 V	5A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	1.70hm @ 2.5A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 50µA	14.2 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	750 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	100W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
IVTD5	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095



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